RECTRON
SEMICONDUCTOR
TECHNICAL SPECIFICATION

HER101G THRU HER108G

HIGH EFFICIENCY GLASS PASSIVATED RECTIFIER

VOLTAGE RANGE 50 to 1000 Volts CURRENT 1.0 Ampere

FEATURES

* Low power loss, high efficiency
* Low leakage
* Low forward voltage
* High current capability
* High speed switching
* High surge capability
* High reliability

MECHANICAL DATA

* Case: Molded plastic
* Epoxy: UL 94V-O rate flame retardant
* Lead: MIL-STD-202E method 208C guaranteed
* Mounting position: Any
* Weight: 0.35 gram

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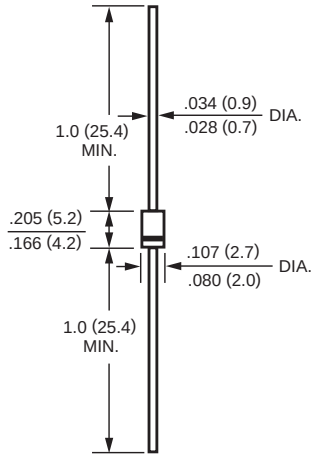

Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

MAXIMUM RATINGS (At T_A = 25°C unless otherwise noted)

RATINGS	SYMBOL	HER101G	HER102G	HER103G	HER104G	HER105G	HER106G	HER107G	HER108G	UNITS
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	300	400	600	800	1000	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	210	280	420	560	700	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	300	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at T_A= 50°C	I_O	1.0								Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	30								Amps
Typical Junction Capacitance (Note 2)	C_J	15					12			pF
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to + 150								°C

ELECTRICAL CHARACTERISTICS (At T_A = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	HER101G	HER102G	HER103G	HER104G	HER105G	HER106G	HER107G	HER108G	UNITS
Maximum Instantaneous Forward Voltage at 1.0A DC	V_F	1.0			1.3		1.70			Volts
Maximum DC Reverse Current at Rated DC Blocking Voltage T_A = 25°C	I_R	5.0								uAmps
Maximum Full Load Reverse Current Average, Full Cycle .375" (9.5mm) lead length at T_L = 55°C		100								uAmps
Maximum Reverse Recovery Time (Note 1)	trr	50					75			nSec

NOTES : 1. Test Conditions: I_F = 0.5A, I_R = 1.0A, I_{RR} = 0.25A
2. Measured at 1 MHz and applied reverse voltage of 4.0 volts

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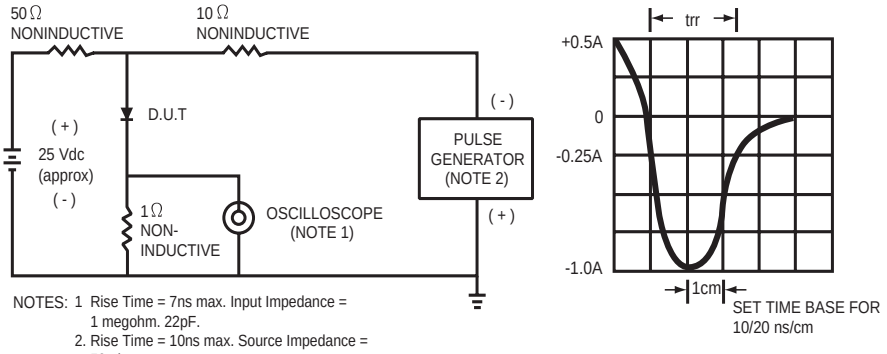
RATING AND CHARACTERISTIC CURVES (HER101G THRU HER108G)

FIG. 1 - TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1 Rise Time = 7ns max. Input Impedance = 1 megohm. 22pF.
2. Rise Time = 10ns max. Source Impedance = 50 ohms.

FIG. 2 - TYPICAL FORWARD CURRENT DERATING CURVE

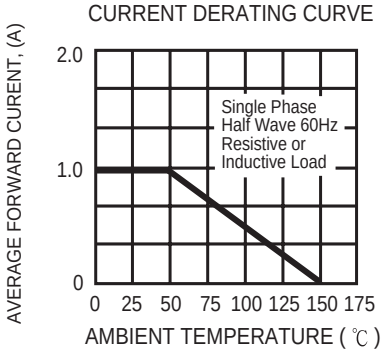


FIG. 3 - TYPICAL REVERSE CHARACTERISTICS

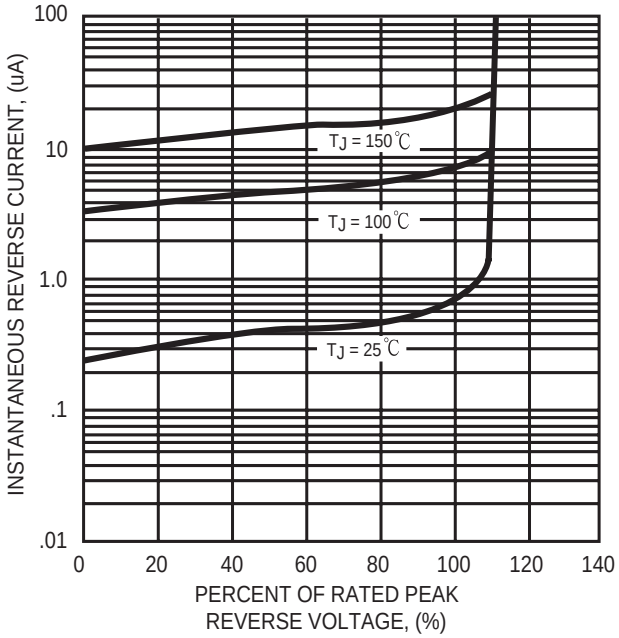


FIG. 4 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

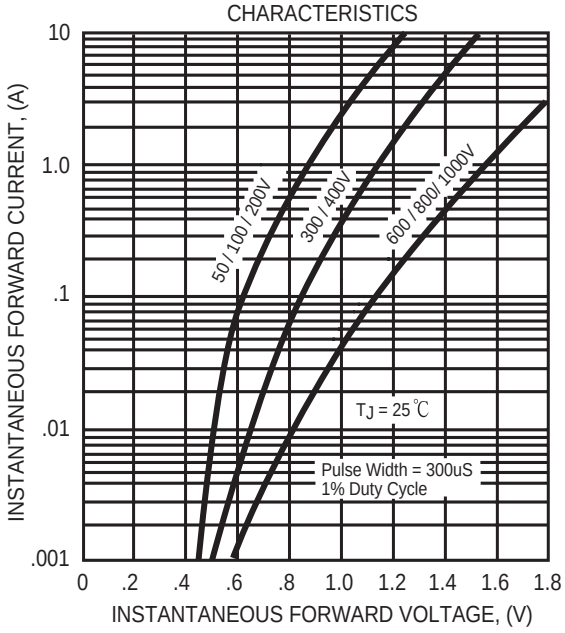


FIG. 5 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

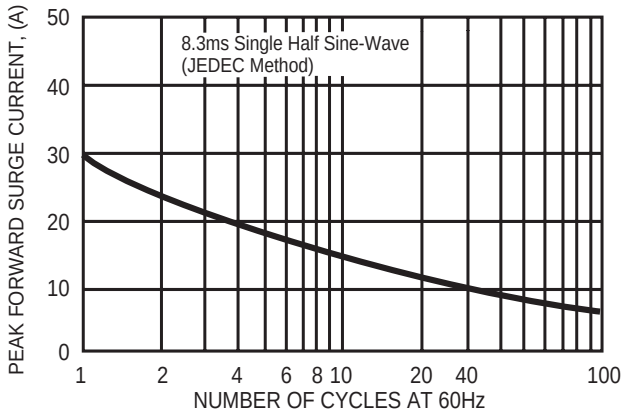


FIG. 6 - TYPICAL JUNCTION CAPACITANCE